

Superconductivity and Electron Tunneling

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Abstract

Tunnel effect between metal layers is analyzed here. A potential difference imposed between two metal layers creates an electron tunneling current, and its relation with the potential depends on the state of the layers, if they are in the normal or in the superconducting state. By analysis of the data the gap of the Lead and other consequences can be inferred.

1 Introduction

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2 Theoretical Approach

The transition rate W for an electron from an occupied state in the layer 1 with momentum \mathbf{p}_1 to a free state in the layer 2 with momentum \mathbf{p}_2 can be calculated by means of the Fermi Golden Rule

like follows:

$$W_{1 \rightarrow 2}^{1e} = \frac{2\pi}{\hbar} |T_{21}|^2 f(\epsilon_{\mathbf{p}_1}) [1 - f(\epsilon_{\mathbf{p}_2})] \delta(\epsilon_{\mathbf{p}_1} - \epsilon_{\mathbf{p}_2}) \delta_{s_1 s_2}, \quad (1)$$

where T_{21} is the transition amplitude, $f(\epsilon_{\mathbf{p}_1})$ the probability that the state \mathbf{p}_1 is occupied and $[1 - f(\epsilon_{\mathbf{p}_2})]$ the probability that the state \mathbf{p}_2 is empty, and the conservation of the energy and spin in the transition are assumed.

The total transition rate from the electrode 1 to the electrode 2 will be

$$W_{1 \rightarrow 2} = \frac{2\pi}{\hbar} \sum_{\substack{s_1, s_2 \\ \mathbf{p}_1, \mathbf{p}_2}} |T_{21}|^2 f(\epsilon_{\mathbf{p}_1}) [1 - f(\epsilon_{\mathbf{p}_2})] \delta(\epsilon_{\mathbf{p}_1} - \epsilon_{\mathbf{p}_2}) \delta_{s_1 s_2}. \quad (2)$$

If the transition hamiltonian does not depend on the spin and couples weakly the electrodes when the applied voltage is small (a valid approximation for the voltages used in this experiment), we can simplify the expression (??):

$$W_{1 \rightarrow 2} = \frac{4\pi}{\hbar} |T|^2 \sum_{\mathbf{p}_1, \mathbf{p}_2} f(\epsilon_{\mathbf{p}_1}) [1 - f(\epsilon_{\mathbf{p}_2})] \delta(\epsilon_{\mathbf{p}_1} - \epsilon_{\mathbf{p}_2}). \quad (3)$$

The transition rate in the opposite way is analogous.

Now we can write explicitly the expression for the current in the $1 \rightarrow 2$ direction:

$$I = e (W_{1 \rightarrow 2} - W_{2 \rightarrow 1}), \quad (4)$$

that is

$$I = \frac{4\pi e}{\hbar} |T|^2 \sum_{\mathbf{p}_1, \mathbf{p}_2} [f(\epsilon_{\mathbf{p}_1}) - f(\epsilon_{\mathbf{p}_2})] \delta(\epsilon_{\mathbf{p}_1} - \epsilon_{\mathbf{p}_2}). \quad (5)$$

If we replace the summatories by integrals, considering that the momentums configure a quasicon-
tinuum, and assuming a voltage difference V be-
tween the electrodes that makes $\mu_2 - \mu_1 = eV$, we
get

$$I = \frac{4\pi e}{\hbar} |T|^2 \times \int_{-\infty}^{\infty} d\epsilon N_1(\epsilon - eV) N_2(\epsilon) [f(\epsilon - eV) - f(\epsilon)], \quad (6)$$

where $N(E)$ is the density of states, needed to per-
form the change from summatories to the integral.

Now three cases can be distinguished, that is,
when both electrodes are metals in the normal
state, when only one of them is in the supercon-
ducting state and when both are in the supercon-
ducting state. The only difference between these
situations is the form of the density of states $N(E)$,
so it must be replaced by the adequate expression.

2.1 Normal-Normal junction

For a sufficient small voltage V , the state densities
can be considered nearly constant, and equation
(??) reads

$$I^{NN} = \frac{4\pi e}{\hbar} |T|^2 N_1(\mu) N_2(\mu) eV, \quad (7)$$

where we have used the fact that

$$\int_{-\infty}^{\infty} d\epsilon [f(\epsilon - eV) - f(\epsilon)] \simeq eV.$$

From this equation can be derived easily the nor-
mal conductance of the junction

$$C^{NN} = \frac{1}{R^{NN}} = \frac{dI^{NN}}{dV} = \frac{4\pi e^2}{\hbar} |T|^2 N_1(\mu) N_2(\mu). \quad (8)$$

2.2 Normal-Superconductor junction

The state density for a superconductor can be de-
rived from considering a continuum spectrum of en-
ergy levels, and hence

$$N_N(\epsilon) d\epsilon = N_S(E) dE. \quad (9)$$

The relation between ϵ and E in the range of
the BCS Theory of Superconductivity is $E_{\mathbf{p}} =$
 $\sqrt{\epsilon_{\mathbf{p}}^2 + \Delta^2}$, with Δ the gap of the superconductor.

So we can get

$$N_S(E) = N_N(\epsilon) \left| \frac{d\epsilon}{dE} \right| = \begin{cases} N_N(\epsilon) \frac{|E|}{\sqrt{E^2 - \Delta^2}}, & |E| > \Delta \\ 0, & |E| \leq \Delta \end{cases}. \quad (10)$$

If we replace this state density in (??) we get the
 I^{NS} , but only up to $|T|^2$ order. There are high
order effects by means of Cooper pair transmission
to the superconducting electrode. Neglecting these
issues, the current for small voltages is

$$I^{NS} = \frac{4\pi e}{\hbar} |T|^2 N_{1N}(\mu) \times \int_{-\infty}^{\infty} dE N_{2S}(E) [f(E - eV) - f(E)] = \frac{4\pi e}{\hbar} |T|^2 N_{1N}(\mu) N_{2N}(\mu) \times \int_{-\infty}^{\infty} dE \frac{|E|}{\sqrt{E^2 - \Delta^2}} [f(E - eV) - f(E)]. \quad (11)$$

It can be expressed in terms of the C^{NN} like
follows:

$$I^{NS} = \frac{C^{NN}}{e} \int_{-\infty}^{\infty} dE \frac{|E|}{\sqrt{E^2 - \Delta^2}} [f(E - eV) - f(E)]. \quad (12)$$

Finally, introducing $x = E - \Delta$ and noting that
Fermi functions are even, we get the expression that
is used for numerical analysis:

$$I^{NS} = \frac{C^{NN}}{e} \int_0^{\infty} dx \frac{x + \Delta}{\sqrt{x(x + 2\Delta)}} \times [f(x + \Delta - eV) - f(x + \Delta + eV)]. \quad (13)$$

From eqrefins, the conductance will be the fol-
lowing

$$C^{NS} = \frac{1}{R^{NS}} = \frac{dI^{NS}}{dV} = \frac{C^{NN}}{e} \int_{-\infty}^{\infty} dE \frac{|E|}{\sqrt{E^2 - \Delta^2}} \frac{\partial f(E - eV)}{\partial V} \quad (14)$$

2.3 Superconductor-Superconductor junction

By analogy with the previous section, we write di-
rectly the expression of the current for this situa-

tion:

$$I^{SS} = \frac{C^{NN}}{e} \int_{-\infty}^{\infty} dE \frac{E^2 [f(E - eV) - f(E)]}{\sqrt{(E^2 - \Delta_1^2)} \sqrt{(E^2 - \Delta_2^2)}}. \quad (15)$$

3 Experimental Method

In order to measure the effect described above in the case of normal-superconductor tunneling, we prepare samples of two metals with different transition temperatures separated by an insulator. We vapor-deposited thin layers of aluminum and lead on a microscope glass slide, leaving the Aluminum layer at the open air for a short period to let some insulating AlO_2 oxide form.

IT HAS TO BE CLEAR THAT WE HAVE A SANDWITCH!!!!!!

1) sample preparation: vacuum chamber (torr?? why?? mean free path), filament, layer thickness (method for calculating it: isotropy or resistance? Justify that the second one gives smaller thickness with Poisson distribution, because we have rare events), ... HOW MUCH/MANY?????!!!!!!!!!!!!!!

2) Cryostat, nitrogen, helium, vacuum pump, manometer, T-P of vapor-pressure He, why don't we have different P's up and down in the cryostat? The T is different... And... HOW MUCH???

3) Measurement: 4 terminals (why? HOW MUCH?), constant steps sized intensity,

4 Results and Analysis

1) Levenberg-Marquard??? The best method: by hand... :-)
 2) Graphs: commentary on ALL the characteristics...
 3) BCS is not totally correct - ρ real density of states is not the BCS's one, phonons,
 4) ...

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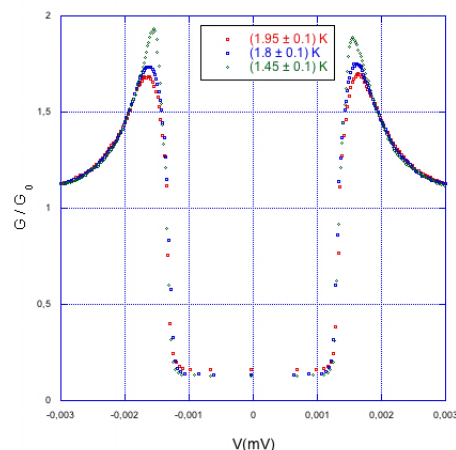


Figure 1: Hola

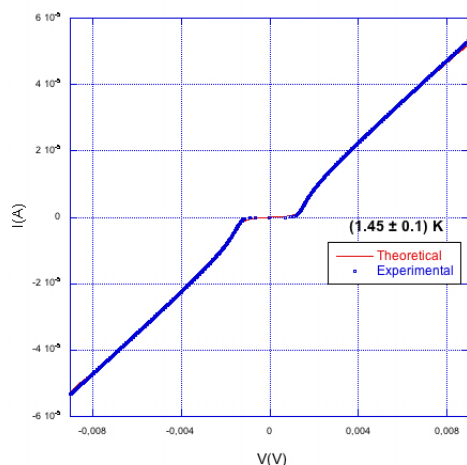


Figure 2: Hola

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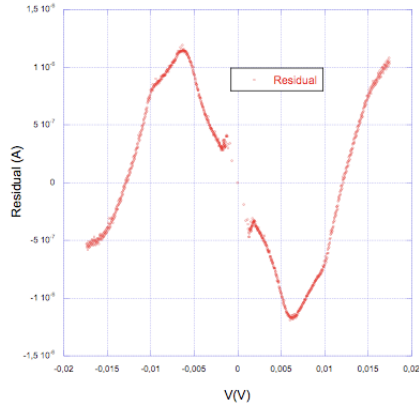


Figure 3: Hola

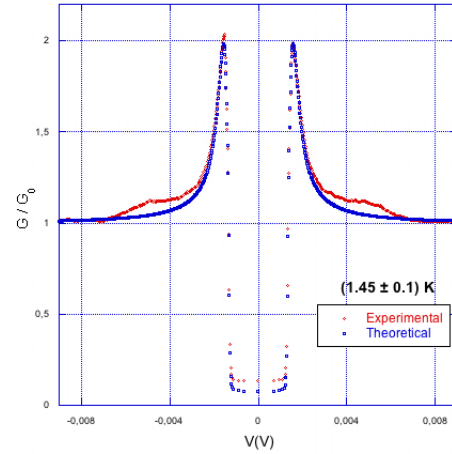


Figure 5: Hola

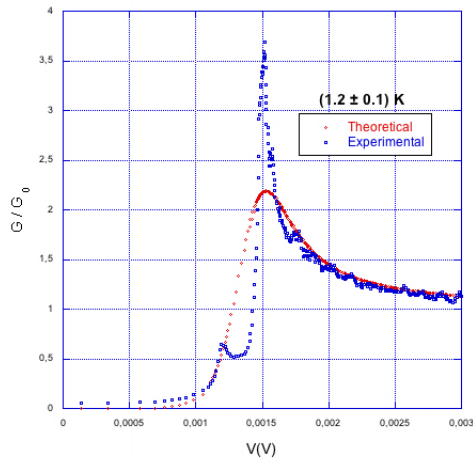


Figure 4: Hola

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